

2. (original) The Micro ElectroMechanical system according to claim 1 wherein:
the corrugated side edge has periodic profile.
3. (original) The Micro ElectroMechanical system according to claim 1 wherein:
the first torsional hinge includes a second corrugated edge.
4. (original) The Micro ElectroMechanical system according to claim 1 wherein the first torsional hinge comprises:
a plurality of wide beam sections that are characterized by a length dimension;
and
a plurality of narrow beam sections that alternate in position with the wide beam sections and are characterized by about the length dimension.
5. (original) The Micro ElectroMechanical system according to claim 1 wherein:
the first torsional hinge is characterized by a minimum width, and an average width, and the average width is between about 1.5 and about 7 times the minimum width.
6. (original) The Micro ElectroMechanical system according to claim 5 wherein:
the average width is between about 2 and about 5 times the minimum width.
7. (original) The Micro ElectroMechanical system according to claim 6 wherein the first torsional hinge has:
a plurality of abrupt increases in width that are interspersed with a plurality of abrupt decreases in width.
8. (original) The Micro ElectroMechanical system according to claim 1 wherein the first torsional hinge comprises:
a monocrystalline silicon material that extends, at least, from the first end to the second end.

9. (original) The Micro ElectroMechanical system according to claim 8 wherein:
the monocrystalline silicon material includes an ion implanted dopant conductive pathway.
10. (original) The Micro ElectroMechanical system according to claim 1 further comprising:
an anchor coupled to the first end of the first torsional hinge;
a resonant member that is dimensioned to resonate at a first frequency and is coupled to the second end of the first torsional hinge;
wherein the first torsional hinge has a phase length that is equal to about an odd multiple of $\pi/2$ in a torsional mode at the first frequency.
11. (original) The Micro ElectroMechanical system according to claim 10 wherein:
the torsional hinge has a phase length that is equal to about $\pi/2$ in the torsional mode at the first frequency.
12. (original) The Micro ElectroMechanical system according to claim 10 further comprising:
a conductive pathway from the anchor, along the first torsional hinge and onto the resonant member.
13. (original) The Micro ElectroMechanical system according to claim 10 wherein:
the resonant member comprises a monocrystalline material layer; and
the elongated beam comprises the monocrystalline material layer.
14. (original) The Micro ElectroMechanical system according to claim 13 further comprising:
an ion implant doped conductive pathway from the anchor, along the first torsional hinge and onto the resonant member.

15. (original) The Micro ElectroMechanical system according to claim 10 wherein:
 - the resonant member is a beam that extends perpendicular to the first torsional hinge and is resonant in a flexural beam mode that includes a first node; and
 - the second end of the first torsional hinge is coupled to the beam at the first node.
16. (original) The Micro ElectroMechanical system according to claim 15 further comprising:
 - a conductive pathway from the anchor, along the first torsional hinge, and onto the beam.
17. (original) The Micro ElectroMechanical system according to claim 16 wherein:
 - the beam comprises a monocrystalline material layer;
 - the first torsional hinge comprises the monocrystalline material layer.
18. (original) The Micro ElectroMechanical system according to claim 17 wherein:
 - the monocrystalline material layer includes a first semiconductor.
19. (original) The Micro ElectroMechanical system according to claim 17 wherein:
 - the anchor comprises:
 - the monocrystalline material layer;
 - a second material layer underlying the monocrystalline material layer; and
 - a base layer underlying the second material layer.
20. (original) The Micro ElectroMechanical system according to claim 19 wherein:
 - the second material layer includes an oxide; and
 - the base layer comprises a semiconductor.

21. (original) The Micro ElectroMechanical system according to claim 20 wherein:
 - the monocristalline material layer comprises silicon;
 - the second material layer comprises silicon dioxide; and
 - the base layer comprises silicon.
22. (original) The Micro ElectroMechanical system according to claim 20 wherein:
 - the monocristalline material layer comprises a III-V semiconductor;
 - the second material layer comprises a perovskite; and
 - the base layer comprises a group IV semiconductor.
23. (original) The Micro ElectroMechanical system according to claim 15 wherein:
 - the beam includes:
 - a first longitudinal edge; and
 - a second longitudinal edge; and
 - the Micro ElectroMechanical system further comprises:
 - a second torsional hinge that has
 - a first end;
 - a second end; and
 - a corrugated side edge;
 - the second end of the first torsional hinge is coupled to the first longitudinal edge of the beam;
 - the second end of the second torsional hinge is coupled to the second longitudinal edge of the beam at the first node; and
 - the second torsional hinge has a phase length that is equal to about an odd multiple of $\pi/2$ in a torsional mode at about the first frequency.

24. (original) The Micro ElectroMechanical system according to claim 23 wherein the flexural beam mode includes a second node; and

the Micro ElectroMechanical system further comprises:

a third torsional hinge that includes:

a first end;

a second end; and

a corrugated side edge;

a fourth torsional hinge that includes:

a first end;

a second end; and

a corrugated side edge;

the second end of the third torsional hinge is coupled first longitudinal edge of the beam at the second node;

the second end of the fourth torsional hinge is coupled to the second longitudinal edge of the beam at the second node;

the third torsional hinge has a phase length that is equal to about an odd multiple of $\pi/2$ in a torsional mode at the first frequency; and

the fourth torsional hinge has a phase length that is equal to about an odd multiple of $\pi/2$ in a torsional mode at the first frequency.

25. (original) The Micro ElectroMechanical system according to claim 24 wherein the first torsional hinge, the second torsional hinge, the third torsional hinge, and the fourth torsional hinge have phase lengths that are about equal to $\pi/2$ at the first frequency.

26. (currently amended) A Micro ElectroMechanical system comprising:
a torsional hinge including
a first torsional hinge that includes:
a first end;
a second end; and
is characterized by:
a length dimension measured between the first end and the second end;
and
a width that is measured perpendicular to the length dimension and varies
as a function of position along the length; and
the torsional hinge comprises:
a first tapered section that is located at the first end and in which the width
increases continuously as a distance from the first end increases; and
a second tapered section that is located at the second end and in which the
width increases continuously as a distance from the second end increases.
27. (CANCEL)
28. (CANCEL)
29. (original) The Micro ElectroMechanical system according to claim 26 wherein:
the torsional hinge comprises:
a first narrow width section at the first end.
30. (original) The Micro ElectroMechanical system according to claim 29 wherein:
the torsional hinge further comprises:
a second narrow width portion at the second end.

31. (original) The Micro ElectroMechanical system according to claim 26 wherein:
a first width measured at the first end has a first value; and
widths measured at all positions between the first end and the second end are equal to at least about the first value.
32. (currently amended) A Micro ElectroMechanical system comprising:
a torsional hinge including
a first torsional hinge that includes:
a first end;
a second end; and
is characterized by:
a length dimension measured between the first end and the second end;
and
a width that is measured perpendicular to the length dimension and varies as a function of position along the length; and
The Micro ElectroMechanical system according to claim 26 wherein:
a second width measured at the second end has a second value; and
the width measured at all positions between the first end and the second end is at least about equal to the second value; and
further comprising:
a anchor coupled to the first end of the torsional hinge; and
a flexural mode resonant beam coupled to the second end of the torsional hinge.
33. (CANCEL)
34. (original) A Micro ElectroMechanical system comprising:
a torsional hinge that includes:
a first end;
a second end; and
a plurality of holes through the torsional hinge.

35. (original) The Micro ElectroMechanical system according to claim 34 further comprising:

an anchor coupled to the first end of the first torsional hinge;
a resonant member that is dimensioned to resonate at a first frequency and is coupled to the second end of the first torsional hinge;
wherein the first torsional hinge has a phase length that is equal to about an odd multiple of $\pi/2$ in a torsional mode at the first frequency.

36. (original) The Micro ElectroMechanical system according to claim 35 wherein:

the resonant member is a beam that extends perpendicular to the first torsional hinge and is resonant in a flexural beam mode that includes a first node; and
the second end of the first torsional hinge is coupled to the beam at the first node.

R E M A R K S

Applicants appreciate the allowance of claims 1-25 and 34-36. The claims have been amended by rewriting claims 26 and 32, and canceling claim 27, 28 and 33. Claims 1-26, 29-32, and 34-36 remain in the application.

Reconsideration of this application is respectfully requested.

Claim Rejections - 35 U.S.C. § 102(b):

Claims 26 and 29 are rejected under 35 U.S.C. § 102(b).

Claim 26 has been amended without prejudice or disclaimer to facilitate the prosecution of this application. Claim 29 now depends on an allowable claim 26 and hence is also in condition for allowance.

Claim Rejections - 35 U.S.C. § 102(e):

Claims 26 and 29-32 are rejected under 35 U.S.C. § 102(e).

Claims 26 and 32 have been amended without prejudice or disclaimer to facilitate the prosecution of this application. Claims 26 and 29-32 are now in condition for allowance.